



QUADRUPLE 2-INPUT NAND GATES WITH SCHMITT TRIGGER INPUTS

Description

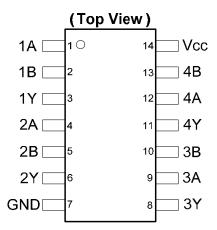
The 74LV132A provides provides four independent 2-input NAND gates with standard push-pull outputs. Each input is a Schmitt Trigger device with a significant amount of hysteresis suiting the device for noisy environments. The device is designed for operation with a power supply range of 2.0V to 5.5V.

The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

The gates perform the Boolean function:

$$Y = \overline{A \bullet B}$$
 or $Y = \overline{A} + \overline{B}$

Pin Assignments



SO-14 / TSSOP-14

Features

- Wide Supply Voltage Range from 2.0V to 5.5V
- Sinks or sources 12mA at V_{CC} = 4.5V
- CMOS low power consumption
- I_{OFF} Supports Partial -Power Down Operation
- Inputs or Outputs accept up to 5.5V
- Inputs can be driven by 3.3V or 5V allowing for voltage translation applications.
- Schmitt Trigger Action at All Inputs
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115)
 - Exceeds 2000-V Human Body Model (A114)
 - Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class I
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Applications

- General Purpose Logic
- Power Down Signal Isolation
- · Wide array of products such as:
 - PCs, networking, notebooks, ultrabooks, netbooks
 - Computer peripherals, hard drives, CD/DVD ROM
 - TV, DVD, DVR, set top box

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

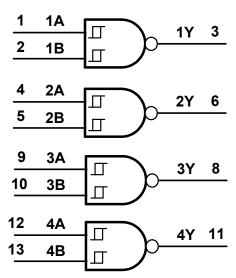
Click for Ordering Information



Pin Descriptions

Pin Number	Pin Name	Description
1	1A	Data Input
2	1B	Data Input
3	1Y	Data Output
4	2A	Data Input
5	2B	Data Input
6	2Y	Data Output
7	GND	Ground
8	3Y	Data Output
9	3A	Data Input
10	3B	Data Input
11	4Y	Data Output
12	4A	Data Input
13	4B	Data Input
14	Vcc	Supply Voltage

Logic Diagram



Function Table

Inp	Output	
Α	В	Y
Н	Н	L
L	X	Н
X	L	Н

Absolute Maximum Ratings (Note 4)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	٧
V _{CC}	Supply Voltage Range	-0.5 to 7.0	V
VI	Input Voltage Range note 4	-0.5 to 7.0	V
lık	Input Clamp Current V _I < 0V	-20	mA
I _{OK}	Output Clamp Current V _O < -0V	-50	mA
lo	Continuous Output Current - 0.5V < V _O V _{CC} + 0.5V	+/- 25	mA
Icc	Continuous Current Through Vcc	50	mA
I _{GND}	Continuous Current Through GND	-50	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
P _{TOT}	Total Power Dissipation	500	mW

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 5)

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage	-	2.0	5.5	V
VI	Input Voltage	-	0	5.5	V
Vo	Output Voltage	-	0	V _{CC}	V
		2.0V	_	-50	mA
l ,	High-Level Output Current	2.3V to 2.7V	_	-2	μΑ
Іон		3.0V to 3.6V	_	-6	mA
		4.5V to 5.5V	_	-12	mA
		2.0V	_	50	μΑ
	Low Lovel Output Current	2.3V to 2.7V	_	2	mA
l _{OL}	Low-Level Output Current	3.0V to 3.6V	_	6	mA
		4.5V to 5.5V	_	12	mA
T _A	Operating Free-Air Temperature	-	-40	+125	°C

Note: 5. Unused inputs should be held at Vcc or Ground.

Electrical Characteristics

				T _A = -40	to +85°C	T _A = -40 1	to +125°C	
Symbol	Parameter	Test Conditions	Vcc	Min	Max	Min	Max	Unit
		-	2.5 V	1	1.75	1	1.75	
V_{T+}	Positive Going Threshold	_	3.3 V	1.31	2.31	1.31	2.31	V
		-	5.0 V	1.95	3.5	1.95	3.5	
		-	2.5 V	0.75	1.5	0.75	1.5	
V_{T-}	Negative Going Threshold	-	3.3 V	0.99	2.07	0.99	2.07	_
		-	5.0 V	1.5	3.05	1.5	3.05	
		-	2.5 V	0.25	1	0.25	1	
V _H	Hysteresis (V _{T+-} V _{T-)}	-	3.3 V	0.33	1.32	0.33	1.32	V
	(11/31/4	-	5.0 V	0.5	2	0.5	2	
		I _{OH} = -50μA	2.0V to 5.5V	V _{CC} -0.1	_	V _{CC} -0.1	_	
	High-Level	I _{OH} = -2mA	2.3V	2.0	_	2.0	-] ,,
Vон	Output Voltage	I _{OH} = -6mA	3.0V	2.48	_	2.48	_	V
		I _{OH} = -12mA	4.5V	3.8	_	3.8	_	
		I _{OL} = 50μA	2.0V to 5.5V	_	0.1	_	0.1	
.,	Low-Level	I _{OL} = 2mA	2.3V	_	0.4	_	0.4	V
V_{OL}	Output Voltage	I _{OL} = 6mA	3.0V	-	0.44	_	0.44]
		I _{OL} = 12mA	4.5V	_	0.55	_	0.55	
l _{OFF}	Power Down Leakage Current	V_{I} or $V_{O} = 0$ to 5.5V	0V	-	5	-	5	μΑ
Iı	Input Current	V _I =GND or 5.5V	0 to 5.5V	_	±1	_	±1	μΑ
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}$ $I_O=0$	5.5V	_	20	_	20	μΑ



Switching Characteristics

Cumbal	Dougrantou	Test	V		T _A = +25°(3	-40 to	+85°C	-40 to	+125°C	Unit	
Symbol	Parameter	Conditions	V _{CC}	Min	Тур.	Max	Min	Max	Min	Max	Unit	
		Figure 4	2.5V ± 0.2V	_	7.9	16.5	1	18.5	1	18.5		
	Propagation	Figure 1	3.3V ± 0.3V	_	5.6	11.9	1	14	1	14	ns	
		C _L =15pF	5.0V ± 0.5V	_	3.9	7.7	1	9	1	9		
t _{PD}	Delay A _N to Y _N		2.5V ± 0.2V	_	10.8	20.2	1	23	1	23		
		Figure 1	Figure 1 C _L =50 pF	3.3V ± 0.3V	-	7.6	15.4	1	17.5	1	17.5	ns
		OL-30 pi	5.0V ± 0.5V	_	5.3	9.7	1	11	1	11		

Operating Characteristics T_A = +25°C

	Parameter		V _{CC}	ТҮР	Unit
	Power Dissipation	F= 10 MHz	3.3V	7.5	pF
C _{pd}	Capacitance per Gate	C _L =50pF	5.0V	11.2	ρг

Noise Characteristics

 $V_{CC} = 3V, C_L = 50pF, T_A = +25^{\circ}C$

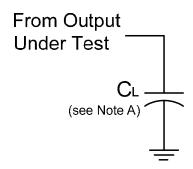
Symbol	Parameter	Min	Тур.	Max	Unit
V _{OL(p)}	Quiet output, maximum dynamic V _{OL}	_	0.2	0.8	V
$V_{OL(V)}$	Quiet output, minimum dynamic V _{OL}	_	-0.1	-0.8	V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}	_	3.1	_	V
$V_{IH(D)}$	High Level dynamic input voltage	2.31	-	-	V
$V_{IL(D)}$	Low Level dynamic input voltage	-	-	0.99	V

Package Characteristics

Ī	Symbol	Parameter	Test Conditions	Vcc	Min	Тур.	Max	Unit
	Ci	Input Capacitance	$V_i = V_{CC} - \text{ or GND}$	2.0 to 5.5V	_	3.3	10	pF



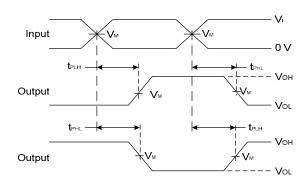
Parameter Measurement Information



V _{cc}	Inp	outs	, V _M	CL
	VI	t _r / t _f		
2.0V to 5.5V	V _{CC}	<3ns	V _{CC} / 2	15pF or 50pF



Voltage Waveform Pulse Duration



Voltage Waveform
Propagation Delay Times
Inverting and Non Inverting Outputs

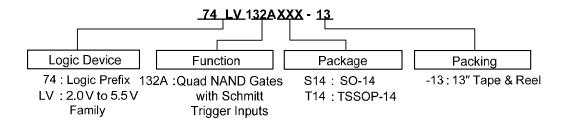
Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate \leq 10MHz
- C. Inputs are measured separately one transition per measurement
- D. t_{PLH} and t_{PHL} are the same as t_{PD}

Figure 1. Load Circuit and Voltage Waveforms



Ordering Information



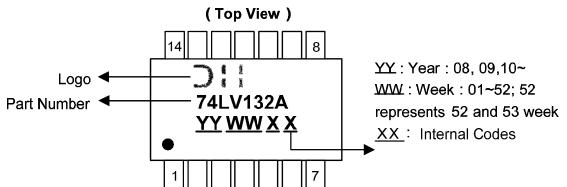
Device	Package Code	Packaging	13" Tape	and Reel
Device	Package Code	(Note 6)	Quantity	Part Number Suffix
74LV132AS14-13	S14	SO-14	2500/Tape & Reel	-13
74LV132AT14-13	T14	TSSOP-14	2500/Tape & Reel	-13

Note:

6. The taping orientation and tape details can be found at http://www.diodes.com/datasheets/ap02007.pdf

Marking Information

(1) SO14, TSSOP14

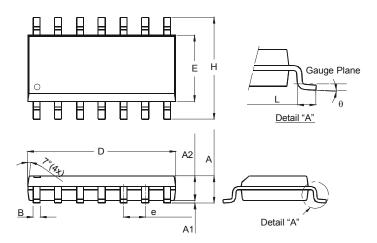


Part Number	Package
74LV132AS14	SO-14
74LV132AT14	TSSOP-14



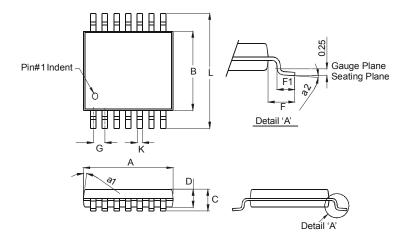
Package Outline Dimensions (All Dimensions in mm)

Package Type: SO-14



SO-14			
Dim	Min	Max	
Α	1.47	1.73	
A 1	0.10	0.25	
A2	1.45 Typ		
В	0.33	0.51	
D	8.53	8.74	
Е	3.80	3.99	
е	1.27 Typ		
Н	5.80	6.20	
L	0.38	1.27	
θ	0°	8°	
All Dimensions in mm			

Package Type: TSSOP-14

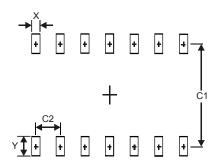


TSSOP-14		
Dim	Min	Max
a1	7° (4X)	
a2	0°	8°
Α	4.9	5.10
В	4.30	4.50
С	_	1.2
D	8.0	1.05
F	1.00 Typ	
F1	0.45	0.75
G	0.65 Typ	
K	0.19	0.30
L	6.40 Typ	
All Dimensions in mm		



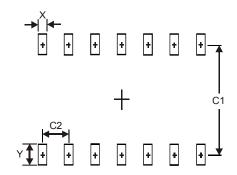
Suggested Pad Layout

Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)	
X	0.45	
Υ	1.45	
C1	5.9	
Co	0.65	



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